UNISONIC TECHNOLOGIES CO., LTD

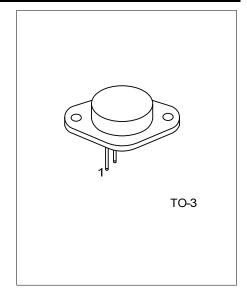
2N2955

PNP SILICON TRANSISTOR

SILICON PNP TRANSISTORS

DESCRIPTION

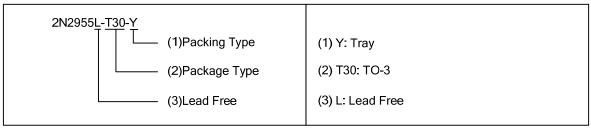
The UTC 2N2955 is a silicon PNP transistor in TO-3 metal case. It is intended for power switching circuits, series and shunt regulators, output stages and high fidelity amplifiers.



ORDERING INFORMATION

Ordering Number	Package	Pin Assignment			Dooking	
		1	2	3	Packing	
2N2955L-T30-Y	TO-3	Е	В	С	Tray	

Note: 3: Case



www.unisonic.com.tw 1 of 2 QW-R205-004,Ca

■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C, unless otherwise specified)

PARAMETERS	SYMBOL	RATINGS	UNITS
Collector-Base Voltage	V _{CBO}	100	V
Collector-Emitter Voltage	V_{CEO}	60	V
Emitter-Base Voltage	V_{EBO}	7	V
Collector-Emitter Voltage	V_{CEV}	70	V
Collector Current	Ic	15	Α
Collector Peak Current(1)	I _{CM}	15	Α
Base Current	l _B	7	Α
Base Peak Current(1)	I _{BM}	15	Α
Total Dissipation at Ta=25°C	P _D	115	W
Max. Operating Junction Temperature	TJ	+200	°C
Storage Temperature	T _{STG}	-65 ~ 200	°C

Note 1.Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (Ta=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
OFF CHARACTERISTICS								
Collector-Emitter Sustaining Voltage	V _{CEO(SUS)}	I _C =200mA, I _B =0V	60			V		
Collector-Emitter Sustaining Voltage	V _{CER(SUS)}	I_{C} =0.2 A, R_{BE} =100 Ω	70			V		
Collector Cut-off Current	I _{CEO}	$V_{CE}=30V,I_{B}=0$			0.7	mA		
Collector Cut-off Current	I _{CEX}	V _{CE} =100V, V _{BE(OFF)} =1.5V V _{CE} =100V, V _{BE(OFF)} =1.5V, Ta=150°C			1.0 5.0	mA		
Emitter Cut-off Current	I _{EBO}	V _{BE} =7V, I _C =0			5.0	mA		
ON CHARACTERISTICS								
DC Current Gain(Note 2)	h _{FE}	I _C =4A,V _{CE} =4V, I _C =10A,V _{CE} =4V	20 5		70			
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	I _C =4A, I _B =400mA I _C =10A, I _B =3.3A			1.1 3.0	V		
Base-Emitter On Voltage	$V_{BE(ON)}$	I _C =4A, V _{CE} =4V			1.5	V		
SECOND BREAKDOWN								
Second Breakdown Collector with Base Forward Biased	ls/b	V _{CE} =60V, T=1.0s, Non-repetitive	2.87			Α		
DYNAMIC CHARACTERISTICS								
Current Gain-Bandwidth Product	f_T	I _C =0.5A, V _{CE} =10V, f=1MHz	2.5			MHz		
Small-Signal Current Gain	h _{FE}	I _C =1A, V _{CE} =4V, f=1kHz	15		120			
Small-Signal Current Gain Cut-off Frequency	fh _{FE}	I _C =1A, V _{CE} =4V, f=1kHz	10			kHz		

Note 2. Pulse Test: PW \leq 300 μ s, Duty Cycle \leq 2%

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